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In this work we generalize the notion of topological electronic states to random lattices in **non-integer dimensions**. By considering a *class D tight-binding model on critical percolating clusters* resulting from a twodimensional site percolation process, we demonstrate that these topological random fractals exhibit the hallmarks of topological insulators while hosting a gapless spectrum.





Our large-scale numerical studies reveal that topological random fractals:

- Display a *robust mobility gap*,
- Support *quantized conductance.*
- Represent a *well-defined thermodynamic phase of matter*.

region  $1.1 < M < 2.9$  shows great enhancement around  $E = 0$  everywhere in the AL regime, indicating that the spectrum is gapless but consists of trivial localized states.

The finite-size scaling analysis further suggests that the *critical properties are not consistent with the expectations of class D* **systems in two dimensions**, hinting to the nontrivial relationship between fractal and integer-dimensional topological states.

#### Abstract

## Model and phase diagram

$$
\mathbb{H} = (2 - M) \sum_{i} \mathbf{c}_{i}^{\dagger} \sigma_{z} \mathbf{c}_{i}
$$
\n
$$
- \frac{t}{2} \sum_{} \mathbf{c}_{i}^{\dagger} \eta_{ij} \mathbf{c}_{j} - \frac{t_{2}}{2} \sum_{\ll ij \gg} \mathbf{c}_{i}^{\dagger} \eta_{ij} \mathbf{c}_{j} + \text{h.c.},
$$
\n(a)\n
$$
\eta_{ij} = \sigma_{z} + i \cos \theta_{ij} \sigma_{x} + i \sin \theta_{ij} \sigma_{y}
$$
\n
$$
0.4
$$
\n
$$
\text{Topological Frae}
$$

### Spectral insulator-Anderson insulator transition

 $M = 0.5$  $M = 0.7$  $M = 0.9$  $M=1$  $M = 1.12$  $M = 1.3$  $M = 1.9$  $M = 2$   $\cdots \cdots$   $M = 2.5$  $M = 2.2$ 

- The mid-spectrum DOS indicates the formation of a spectral gap for  $M < 1.1$ , while for  $1.1 < M < 2.9$  the system is in a gapless AL phase. Both phases separated by the **tricritical metallic point**  $(t_2^c, M_c) \approx (0, 1.1)$  are insulating.
- The inverse participation ratio in the

# Properties of topological random fractal phase

- The gapped-gapless phase transition coincides with the trivialtopological fractal transition.
- If the energy is in the mobility gap, the conductance (for samples larger than the localization length) remains quantized.
- The quantization develops rapidly when moving from the tricritical point towards the topological phase**. Larger systems exhibit on average more precise quantization**, indicating that the random fractal phase is a well-defined *thermodynamic phase of matter*.

# Finite-size scaling of two-terminal conductance

Near the transition, one expects that the configuration-averaged conductance obeys a *single-parameter scaling* hypothesis in the large system limit. By calculating the conductance as a function of the second-nearest-neighbour hopping, we can show that the *standard two-dimensional class D scaling does not match the numerical evidence.*

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# Topological Random Fractals













- This model **breaks** *TR* and **satisfies** *PH* symmetries, hence belonging to the **class** *D*.
- On a square lattice in the clean limit, the model supports topological phases with **nonzero Chern number**.



# Main findings